

## 800mA Fixed Output CMOS LDO

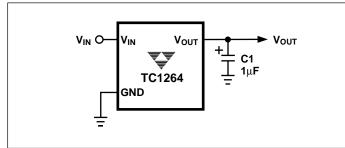
## FEATURES

- Very Low Dropout Voltage
- Guaranteed 800mA Output
- High Output Voltage Accuracy
- Standard or Custom Output Voltages
- Over-Current and Over-Temperature Protection

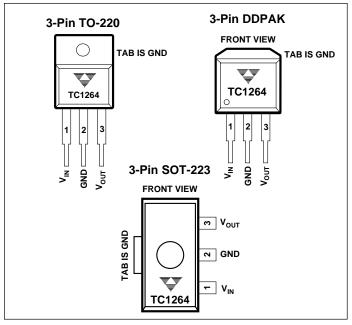
### APPLICATIONS

- Battery-Operated Systems
- Portable Computers
- Medical Instruments
- Instrumentation
- Cellular / GSM / PHS Phones
- Linear Post-Regulator for SMPS
- Pagers

#### **TYPICAL APPLICATION**



#### **PIN CONFIGURATION**



## **GENERAL DESCRIPTION**

The TC1264 is a fixed output, high accuracy (typically  $\pm 0.5\%$ ) CMOS low dropout regulator. Designed specifically for battery-operated systems, the TC1264's CMOS construction eliminates wasted ground current, significantly extending battery life. Total supply current is typically 80  $\mu$ A at full load (20 to 60 times lower than in bipolar regulators!).

TC1264 key features include ultra low noise, very low dropout voltage (typically 450mV at full load), and fast response to step changes in load. The TC1264 incorporates both over-temperature and over-current protection. The TC1264 is stable with an output capacitor of only 1 $\mu$ F and has a maximum output current of 800mA. It is available in 3-Pin SOT-223, 3-Pin TO-220, and 3-Pin DDPAK packages.

## **ORDERING INFORMATION**

Part Number	Package	Junction Temperature Range
TC1264-xxVDB	3-Pin SOT-223	– 40°C to +125°C
TC1264-xxVAB	3-Pin TO-220	- 40°C to +125°C
TC1264-xxVEB	3-Pin DDPAK	– 40°C to +125°C

#### Available Output Voltages:

1.8, 2.5, 3.0, 3.3 xx indicates ouput voltages

Other output voltages are available. Please contact TelCom Semiconductor for details.

## **ABSOLUTE MAXIMUM RATINGS\***

Input Voltage	6.5V
Output Voltage	$(V_{SS} - 0.3)$ to $(V_{IN} + 0.3)$
Power Dissipation	Internally Limited (Note 7)
Operating Temperature	– 40°C < T <sub>J</sub> < 125°C
Storage Temperature	– 65°C to +150°C

Maximum Voltage on Any Pin ..... VIN + 0.3V to - 0.3V Lead Temperature (Soldering, 10 Sec.) ..... +260°C

\*Absolute Maximum Ratings indicate device operation limits beyond damage may occur. Device operation beyond the limits listed in Electrical Characteristics is not recommended.

**ELECTRICAL CHARACTERISTICS:**  $V_{IN} = V_R + 1.5V$  (Note 1),  $I_L = 100\mu A$ ,  $C_L = 3.3\mu F$ ,  $T_A = 25^{\circ}C$ , unless otherwise specified. BOLDFACE type specifications apply for junction temperatures of -40°C to +125°C.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
V <sub>IN</sub>	Input Operating Voltage	(Note 2)	2.7	_	6.0	V
IOUTMAX	Maximum Output Current		800		_	mA
Vout	Output Voltage	$V_{R} \ge 2.5V$ $V_{R} = 1.8V$		$V_{R} \pm 0.5\%$ $V_{R} \pm 0.5\%$		V
$\Delta V_{OUT} / \Delta T$	V <sub>OUT</sub> Temperature Coefficient	Note 3	_	40	—	ppm/°C
$\Delta V_{OUT} / \Delta V_{IN}$	Line Regulation	$(V_R + 1V) \le V_{IN} \le 6V$	—	0.007	0.35	%
ΔVουτ/Vout	Load Regulation	$I_L = 0.1 \text{mA to } I_{OUTMAX}$ (Note 4)	-0.01	0.002	0	%/mA
V <sub>IN</sub> – V <sub>OUT</sub>	Dropout Voltage	$\label{eq:VR} \begin{array}{c} V_R \geq 2.5 \text{V}, \ I_L = 100 \mu \text{A} \\ I_L = 100 \text{mA} \\ I_L = 300 \text{mA} \\ I_L = 500 \text{mA} \\ I_L = 800 \text{mA} \\ V_R = 1.8 \text{V}, \ I_L = 500 \text{mA} \\ I_L = 800 \text{mA} \\ I_L = 800 \text{mA} \\ (\text{Note 5}) \end{array}$		20 50 150 260 450 700 890	30 160 480 800 1300 1000 1400	mV
I <sub>DD</sub>	Supply Current	$I_L = 0$	_	80	130	μA
PSRR	Power Supply Rejection Ratio	F ≤ 1kHz	_	64	—	dB
I <sub>OUTSC</sub>	Output Short Circuit Current	V <sub>OUT</sub> = 0V		1200	_	mA
$\Delta V_{OUT} / \Delta P_D$	Thermal Regulation	Note 6	_	0.04		V/W
eN	Output Noise	$I_L = I_{OUTMAX}, F = 10 kHz$	_	260	—	nV/√ <del>Hz</del>

**NOTES:** 1.  $V_R$  is the regulator output voltage setting.

2. The minimum  $V_{IN}$  has to justify the conditions:  $V_{IN\geq} V_R + V_{DROPOUT}$  and  $V_{IN\geq} 2.7V$  for  $I_L = 0.1$ mA to  $I_{OUTMAX}$ .

3. T<sub>C</sub> V<sub>OUT</sub> = (V<sub>OUTMAX</sub> – V<sub>OUTMIN</sub>) x 10<sup>6</sup>

V<sub>OUT</sub> x ΔT

4. Regulation is measured at a constant junction temperature using low duty cycle pulse testing. Load regulation is tested over a load range from 0.1mA to the maximum specified output current. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

5. Dropout voltage is defined as the input to output differential at which the output voltage drops 2% below its nominal value measured at a 1.5V differential.

6. Thermal Regulation is defined as the change in output voltage at a time T after a change in power dissipation is applied, excluding load or line regulation effects. Specifications are for a current pulse equal to  $I_{LMAX}$  at  $V_{IN}$  = 6V for T = 10msec.

7. The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature, and the thermal resistance from junction-to-air (i.e. T<sub>A</sub>, T<sub>J</sub>, θ<sub>JA</sub>). Exceeding the maximum allowable power dissipation causes the device to initiate thermal shutdown. Please see Thermal Considerations section of this data sheet for more details.

### **DETAILED DESCRIPTION**

The TC1264 is a precision, fixed output LDO. Unlike bipolar regulators, the TC1264 supply current does not increase with load current. In addition,  $V_{OUT}$  remains stable and within regulation at very low load currents (an important consideration in RTC and CMOS RAM battery backup applications). Figure 1 shows a typical application circuit.

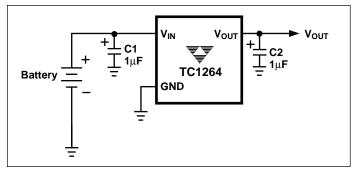


Figure 1: Typical Application Circuit

#### **Output Capacitor**

A 1 $\mu$ F (min) capacitor from V<sub>OUT</sub> to ground is required. The output capacitor should have an effective series resistance of 5 $\Omega$  or less. A 1 $\mu$ F capacitor should be connected from V<sub>IN</sub> to GND if there is more than 10 inches of wire between the regulator and the AC filter capacitor, or if a battery is used as the power source. Aluminum electrolytic or tantalum capacitor types can be used. (Since many aluminum electrolytic capacitors freeze at approximately – 30°C, solid tantalums are recommended for applications operating below –25°C.) When operating from sources other than batteries, supply-noise rejection and transient response can be improved by increasing the value of the input and output capacitors and employing passive filtering techniques.

### **Thermal Considerations**

#### Thermal Shutdown

Integrated thermal protection circuitry shuts the regulator off when die temperature exceeds 160°C. The regulator remains off until the die temperature drops to approximately 150°C.

#### **Power Dissipation**

The amount of power the regulator dissipates is primarily a function of input and output voltage, and output current. The following equation is used to calculate worst case *actual* power dissipation:

$$\begin{split} P_D &\approx (V_{INMAX} - V_{OUTMIN}) I_{LOADMAX} \\ \\ Where: \quad P_D &= \text{worst case actual power dissipation} \\ V_{INMAX} &= \text{maximum voltage on } V_{IN} \\ V_{OUTMIN} &= \text{minimum regulator output voltage} \\ I_{LOADMAX} &= \text{maximum output (load) current} \end{split}$$

#### Equation 1.

The maximum *allowable* power dissipation (Equation 2) is a function of the maximum ambient temperature  $(T_{AMAX})$ , the maximum allowable die temperature  $(125^{\circ}C)$  and the thermal resistance from junction-to-air  $(\theta_{JA})$ .

$$\mathsf{P}_{\mathsf{DMAX}} = \frac{(\mathsf{T}_{\mathsf{JMAX}} - \mathsf{T}_{\mathsf{AMAX}})}{\theta_{\mathsf{JA}}}$$

Where all terms are previously defined.

Equation 2.

Table 1 shows various values of  $\theta_{JA}$  for the TC1264 mounted on a 1/16 inch, 2-layer PCB with 1 oz. copper foil.

# Table 1. Thermal Resistance Guidelines for TC1264 in3-Pin SOT-223 Package

Copper Area (Topside)*	Copper Area (Backside)	Board Area	Thermal Resistance (θ <sub>JA</sub> )
2500 sq mm	2500 sq mm	2500 sq mm	45°C/W
1000 sq mm	2500 sq mm	2500 sq mm	45°C/W
225 sq mm	2500 sq mm	2500 sq mm	53°C/W
100 sq mm	2500 sq mm	2500 sq mm	59°C/W
1000 sq mm	1000 sq mm	1000 sq mm	52°C/W
1000 sq mm	0 sq mm	1000 sq mm	55°C/W

**NOTES:** \*Tab of device attached to topside copper

## Table 2. Thermal Resistance Guidelines for TC1264 in3-Pin DDPAK/TO-220 Package

Copper Area (Topside)*	Copper Area (Backside)	Board Area	Thermal Resistance (θ <sub>JA</sub> )
2500 sq mm	2500 sq mm	2500 sq mm	25°C/W
1000 sq mm	2500 sq mm	2500 sq mm	27°C/W
125 sq mm	2500 sq mm	2500 sq mm	35°C/W

**NOTES:** \*Tab of device attached to topside copper

Equation 1 can be used in conjunction with Equation 2 to ensure regulator thermal operation is within limits. For example:

FIND: 1. Actual power dissipation 2. Maximum allowable dissipation

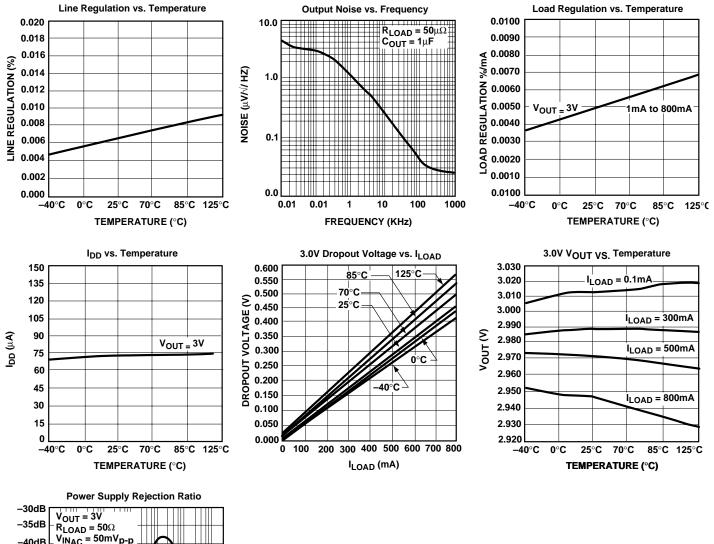
Actual power dissipation:

$$P_{D} \approx (V_{INMAX} - V_{OUTMIN})I_{LOADMAX}$$
  
= [(3.3 x 1.1) - (2.7 x .995)]275 x 10<sup>-3</sup>  
= 260mW

Maximum allowable power dissipation:

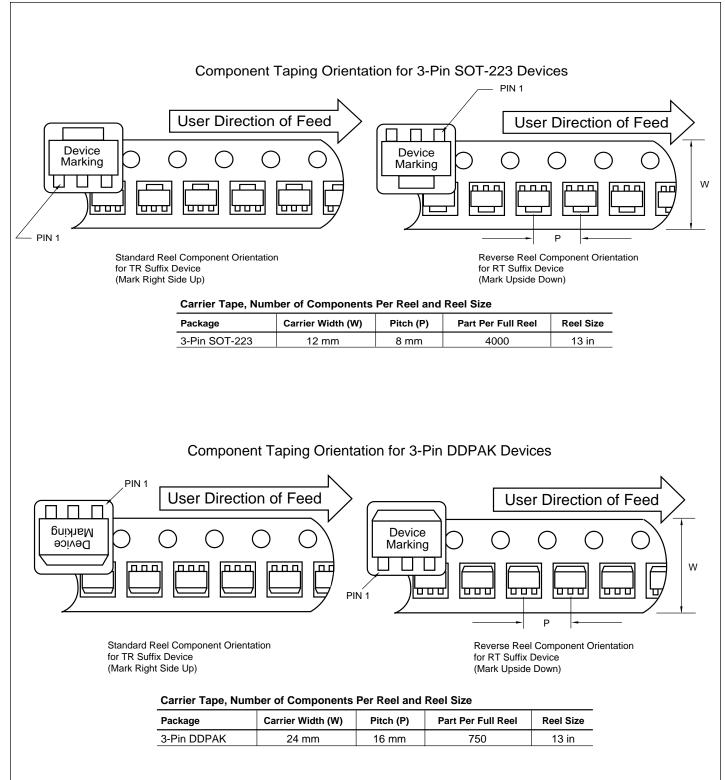
In this example, the TC1264 dissipates a maximum of only 260mW; far below the allowable limit of 508mW. In a similar manner, Equation 1 and Equation 2 can be used to calculate maximum current and/or input voltage limits. For example, the maximum allowable V<sub>IN</sub> is found by substituting the maximum allowable power dissipation of 508mW into Equation 1, from which V<sub>INMAX</sub> = 4.6V.

## **TYPICAL CHARACTERISTICS**

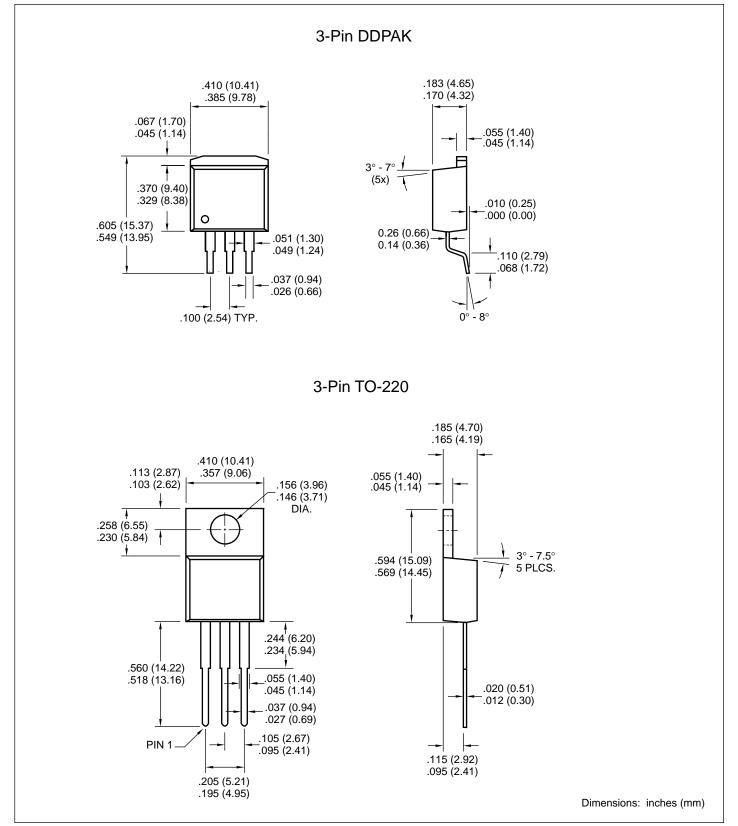


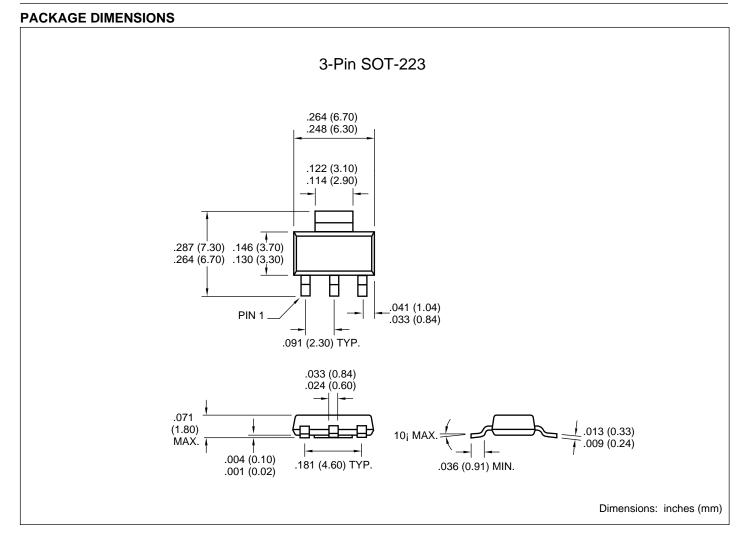
 $V_{INAC} = 50 m V_{p-p}$ -40dB -45dB PSRR (dB) -50dB -55dB C<sub>OUT</sub> = 1μF -60dB -65dB -70dB -75dB -80dB 1K 10K 100K 10 100 1M

#### **TAPING FORMS**



#### PACKAGE DIMENSIONS





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